



PSMN5R0-80BS

N-channel 80 V, 5.1 mΩ standard level MOSFET in D2PAK

Rev. 1 — 20 March 2012

Product data sheet

1. Product profile

1.1 General description

Standard level N-channel MOSFET in SOT404 package qualified to 175 °C. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

1.2 Features and benefits

- High efficiency due to low switching and conduction losses
- Suitable for standard level gate drive sources

1.3 Applications

- DC-to-DC converters
- Load switching
- Motor control
- Server power supplies

1.4 Quick reference data

Table 1. Quick reference data

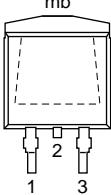
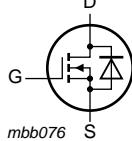
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25 \text{ }^\circ\text{C}; T_j \leq 175 \text{ }^\circ\text{C}$	-	-	80	V
I_D	drain current	$T_{mb} = 25 \text{ }^\circ\text{C}; V_{GS} = 10 \text{ V};$ see Figure 1	[1]	-	100	A
P_{tot}	total power dissipation	$T_{mb} = 25 \text{ }^\circ\text{C};$ see Figure 2	-	-	270	W
T_j	junction temperature		-55	-	175	$^\circ\text{C}$
Static characteristics						
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 100 \text{ }^\circ\text{C};$ see Figure 13 ; see Figure 12	-	7.19	8.5	$\text{m}\Omega$
		$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ }^\circ\text{C};$ see Figure 12	-	4.36	5.1	$\text{m}\Omega$
Dynamic characteristics						
Q_{GD}	gate-drain charge	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; V_{DS} = 40 \text{ V};$ see Figure 14 ; see Figure 15	-	21	-	nC
$Q_{G(tot)}$	total gate charge		-	101	-	nC
Avalanche ruggedness						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$V_{GS} = 10 \text{ V}; T_{j(\text{init})} = 25 \text{ }^\circ\text{C};$ $I_D = 100 \text{ A}; V_{sup} \leq 80 \text{ V}; R_{GS} = 50 \Omega;$ unclamped	-	-	396	mJ

[1] Continuous current is limited by package

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2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	D	drain ^[1]		
3	S	source		
mb	D	mounting base; connected to drain		
SOT404 (D2PAK)				

[1] It is not possible to make connection to pin 2

3. Ordering information

Table 3. Ordering information

Type number	Package			Version
	Name	Description		
PSMN5R0-80BS	D2PAK	plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)		SOT404

4. Marking

Table 4. Marking codes

Type number	Marking code
PSMN5R0-80BS	PSMN5R0-80BS

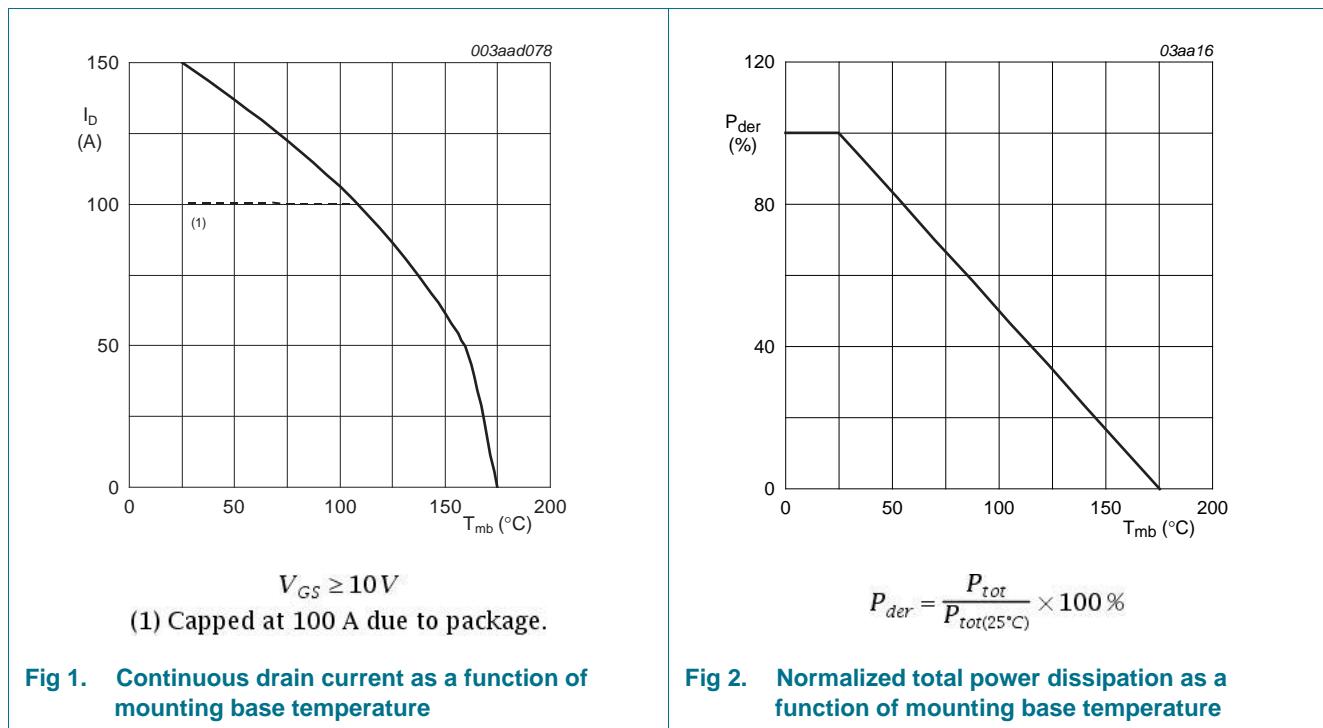
5. Limiting values

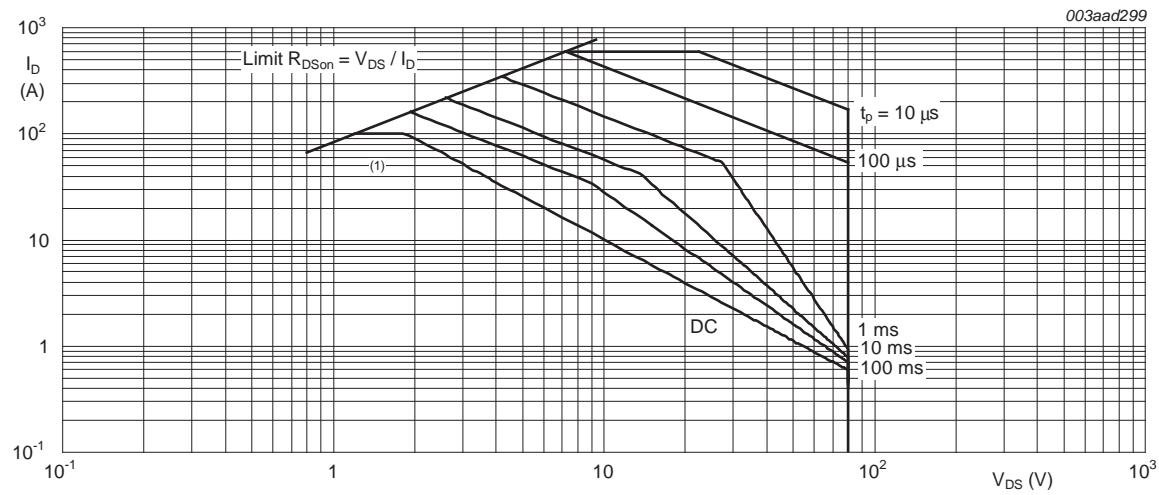
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit	
V_{DS}	drain-source voltage	$T_j \geq 25^\circ\text{C}; T_j \leq 175^\circ\text{C}$	-	80	V	
V_{DGR}	drain-gate voltage	$T_j \geq 25^\circ\text{C}; T_j \leq 175^\circ\text{C}; R_{GS} = 20\text{ k}\Omega$	-	80	V	
V_{GS}	gate-source voltage		-20	20	V	
I_D	drain current	$V_{GS} = 10\text{ V}; T_{mb} = 100^\circ\text{C}$; see Figure 1	[1]	-	100	A
		$V_{GS} = 10\text{ V}; T_{mb} = 25^\circ\text{C}$; see Figure 1	[1]	-	100	A
I_{DM}	peak drain current	pulsed; $t_p \leq 10\text{ }\mu\text{s}; T_{mb} = 25^\circ\text{C}$; see Figure 3	-	598	A	
P_{tot}	total power dissipation	$T_{mb} = 25^\circ\text{C}$; see Figure 2	-	270	W	
T_{stg}	storage temperature		-55	175	°C	
T_j	junction temperature		-55	175	°C	
$T_{sld(M)}$	peak soldering temperature		-	260	°C	
Source-drain diode						
I_S	source current	$T_{mb} = 25^\circ\text{C}$	[1]	-	100	A
I_{SM}	peak source current	pulsed; $t_p \leq 10\text{ }\mu\text{s}; T_{mb} = 25^\circ\text{C}$	-	598	A	
Avalanche ruggedness						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$V_{GS} = 10\text{ V}; T_{j(init)} = 25^\circ\text{C}; I_D = 100\text{ A}; V_{sup} \leq 80\text{ V}; R_{GS} = 50\Omega$; unclamped	-	396	mJ	

[1] Continuous current is limited by package





$T_{mb} = 25 \text{ }^{\circ}\text{C}$; I_{DM} is single pulse
(1) Capped at 100 A due to package.

Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j\text{-mb})}$	thermal resistance from junction to mounting base	see Figure 4	-	0.3	0.56	K/W
$R_{th(j\text{-a})}$	thermal resistance from junction to ambient	Minimum footprint; mounted on a printed circuit board	-	50	-	K/W

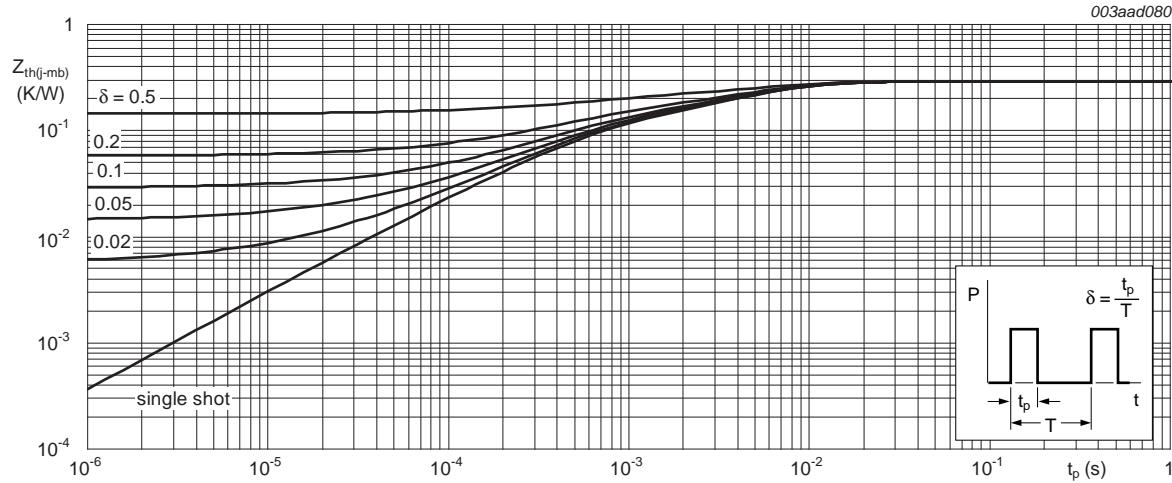


Fig 4. Transient thermal impedance from junction to mounting base as a function of pulse duration; typical values

7. Characteristics

Table 7. Characteristics

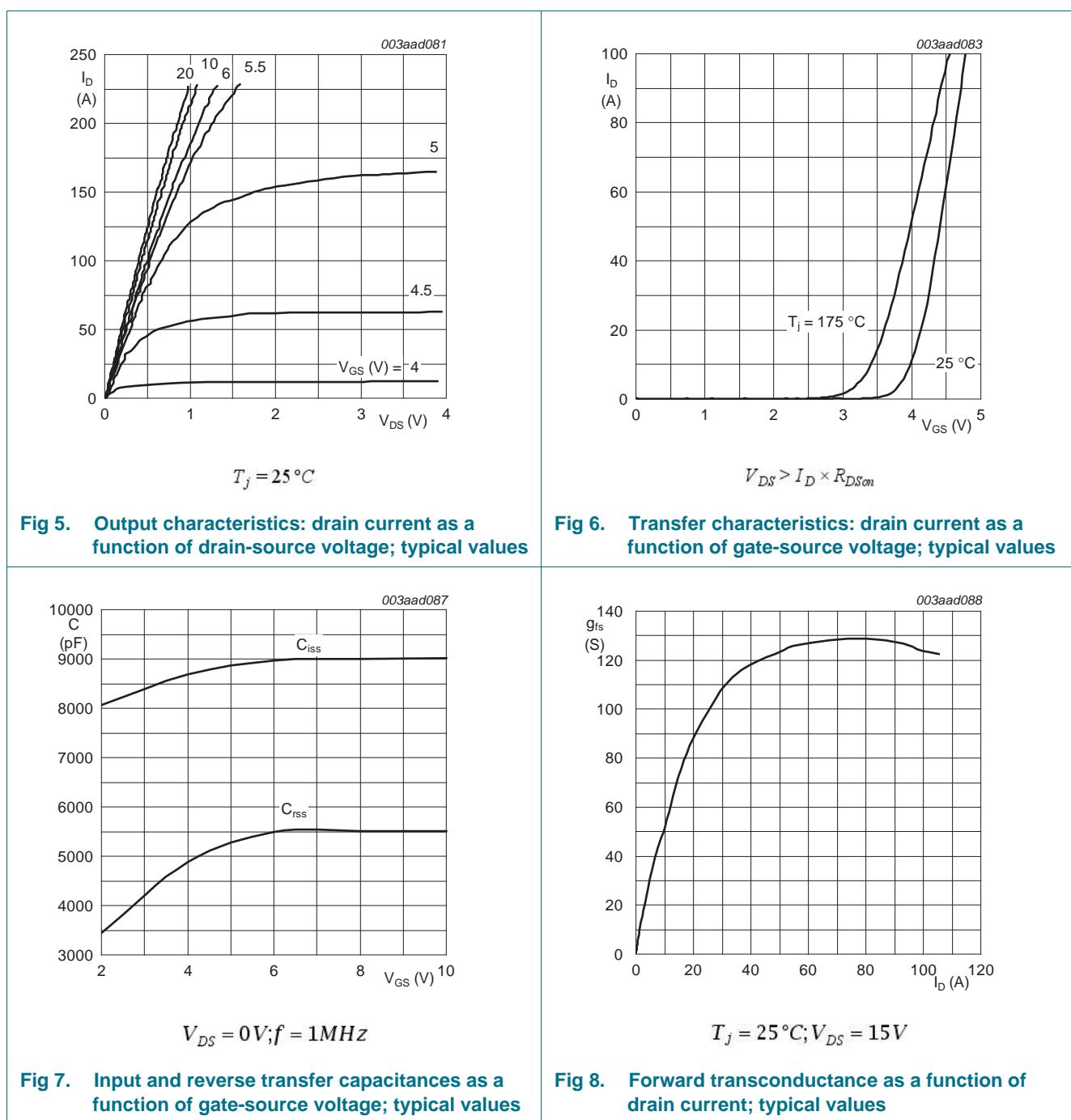
Tested to JEDEC standards where applicable.

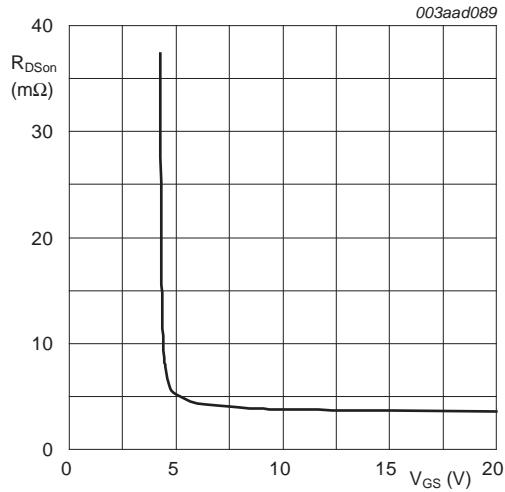
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55^\circ C$	73	-	-	V
		$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25^\circ C$	80	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 mA; V_{DS} = V_{GS}; T_j = 175^\circ C$ see Figure 10	1	-	-	V
		$I_D = 1 mA; V_{DS} = V_{GS}; T_j = -55^\circ C$ see Figure 10	-	-	4.6	V
		$I_D = 1 mA; V_{DS} = V_{GS}; T_j = 25^\circ C$ see Figure 11 ; see Figure 10	2	3	4	V
I_{DSS}	drain leakage current	$V_{DS} = 80 V; V_{GS} = 0 V; T_j = 25^\circ C$	-	0.02	8	μA
		$V_{DS} = 80 V; V_{GS} = 0 V; T_j = 125^\circ C$	-	-	150	μA
I_{GSS}	gate leakage current	$V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25^\circ C$	-	10	100	nA
		$V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25^\circ C$	-	10	100	nA
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10 V; I_D = 25 A; T_j = 175^\circ C$ see Figure 12 ; see Figure 13	-	10.46	12.3	Ω
		$V_{GS} = 10 V; I_D = 25 A; T_j = 100^\circ C$ see Figure 13 ; see Figure 12	-	7.19	8.5	$m\Omega$
		$V_{GS} = 10 V; I_D = 25 A; T_j = 25^\circ C$ see Figure 12	-	4.36	5.1	$m\Omega$
R_G	internal gate resistance (AC)	$f = 1 MHz$	-	0.95	-	Ω
Dynamic characteristics						
$Q_{G(tot)}$	total gate charge	$I_D = 0 A; V_{DS} = 0 V; V_{GS} = 10 V$	-	87	-	nC
		$I_D = 25 A; V_{DS} = 40 V; V_{GS} = 10 V$	-	101	-	nC
Q_{GS}	gate-source charge	see Figure 14 ; see Figure 15	-	26	-	nC
$Q_{GS(th)}$	pre-threshold gate-source charge		-	18	-	nC
$Q_{GS(th-pl)}$	post-threshold gate-source charge		-	8	-	nC
Q_{GD}	gate-drain charge		-	21	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	$I_D = 25 A; V_{DS} = 40 V$; see Figure 14 ; see Figure 15	-	4.2	-	V
C_{iss}	input capacitance	$V_{DS} = 40 V; V_{GS} = 0 V; f = 1 MHz$	-	6793	-	pF
C_{oss}	output capacitance	$T_j = 25^\circ C$; see Figure 16	-	913	-	pF
C_{rss}	reverse transfer capacitance		-	350	-	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 40 V; R_L = 0.5 \Omega; V_{GS} = 10 V$	-	33	-	ns
t_r	rise time	$R_{G(ext)} = 4.7 \Omega$	-	21	-	ns
$t_{d(off)}$	turn-off delay time		-	73	-	ns
t_f	fall time		-	14	-	ns

Table 7. Characteristics ...continued

Tested to JEDEC standards where applicable.

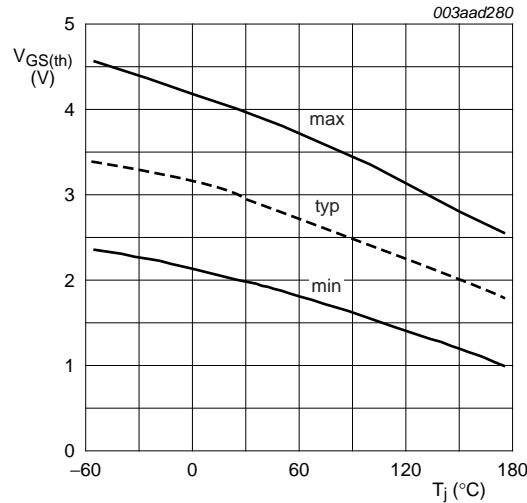
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Source-drain diode						
V_{SD}	source-drain voltage	$I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$; see Figure 17	-	0.8	1.2	V
t_{rr}	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = 100 \text{ A}/\mu\text{s};$	-	56	-	ns
Q_r	recovered charge	$V_{GS} = 0 \text{ V}; V_{DS} = 40 \text{ V}$	-	116	-	nC





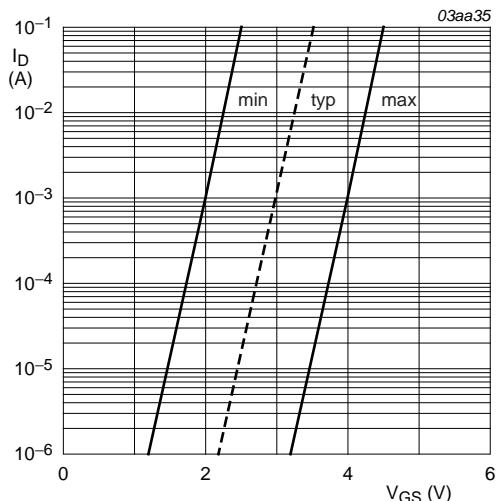
$T_j = 25^\circ C; I_D = 25A$

Fig 9. Drain-source on-state resistance as a function of gate-source voltage; typical values



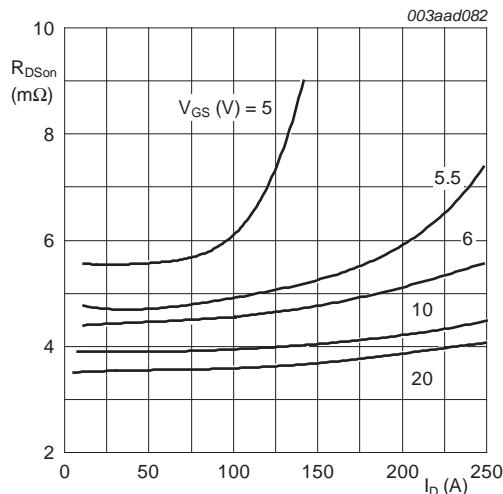
$I_D = 1 mA; V_{DS} = V_{GS}$

Fig 10. Gate-source threshold voltage as a function of junction temperature



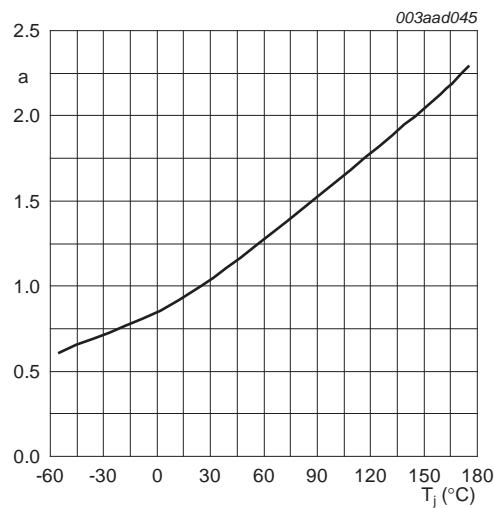
$T_j = 25^\circ C; V_{DS} = 5V$

Fig 11. Sub-threshold drain current as a function of gate-source voltage



$T_j = 25^\circ C$

Fig 12. Drain-source on-state resistance as a function of drain current; typical values



$$a = \frac{R_{DSon}}{R_{DSon}(25^\circ\text{C})}$$

Fig 13. Normalized drain-source on-state resistance factor as a function of junction temperature

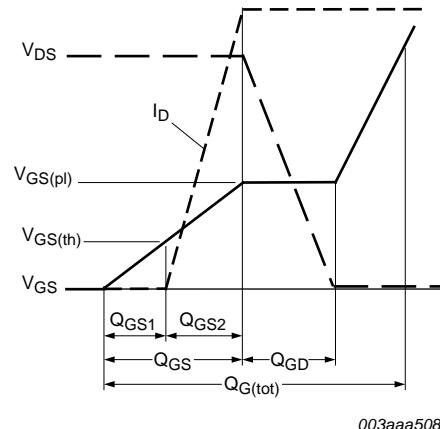
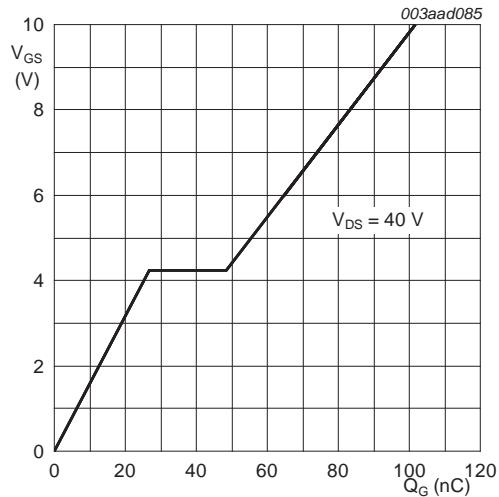
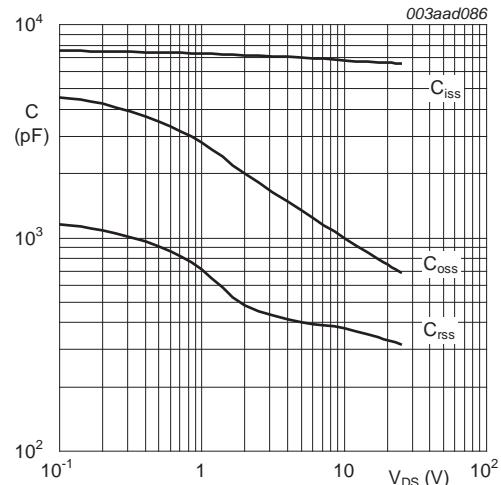


Fig 14. Gate charge waveform definitions



$$T_j = 25^\circ\text{C}; I_D = 25\text{A}$$

Fig 15. Gate-source voltage as a function of gate charge; typical values



$$V_{GS} = 0\text{V}; f = 1\text{MHz}$$

Fig 16. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

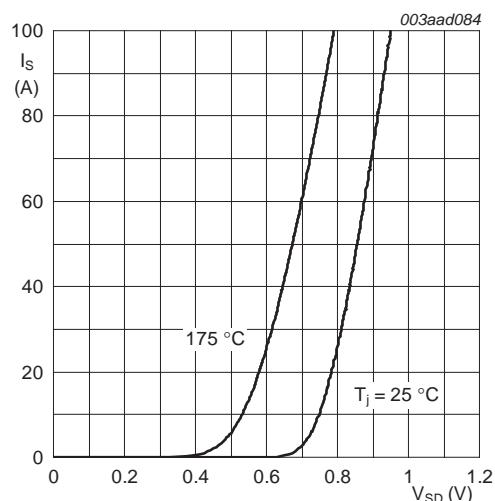
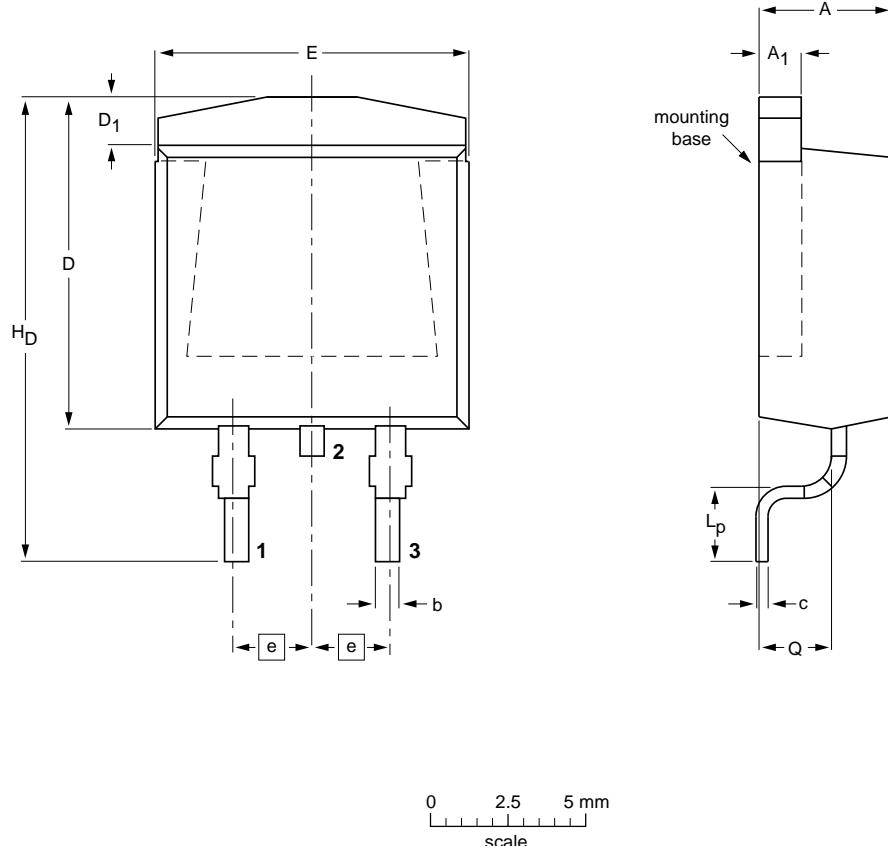
 $V_{GS} = 0 \text{ V}$

Fig 17. Source current as a function of source-drain voltage; typical values

8. Package outline

Plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)

SOT404



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁	b	c	D _{max.}	D ₁	E	e	L _p	H _D	Q
mm	4.50 4.10	1.40 1.27	0.85 0.60	0.64 0.46	11	1.60 1.20	10.30 9.70	2.54	2.90 2.10	15.80 14.80	2.60 2.20

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT404						05-02-11 06-03-16

Fig 18. Package outline SOT404 (D2PAK)

9. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PSMN5R0-80BS v.1	20120320	Product data sheet	-	-

10. Legal information

10.1 Data sheet status

Document status ^[1] ^[2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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For sales office addresses, please send an email to: salesaddresses@nexperia.com

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